TOSHIBA Field Effect Transistor Silicon N Channel MOS Type

SSM3K15FS

High Speed Switching Applications Analog Switching Applications

• Compact package suitable for high-density mounting

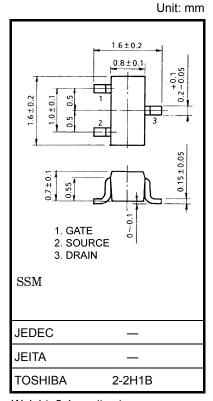
• Low ON-resistance : $R_{on} = 4.0 \Omega \text{ (max)} \text{ (@V}_{GS} = 4 \text{ V)}$

: $R_{on} = 7.0 \Omega (max) (@V_{GS} = 2.5 V)$

Absolute Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit	
Drain-Source voltage		V_{DS}	30	V	
Gate-Source voltage		V _{GSS}	±20	V	
Drain current	DC	ID	100	mA	
	Pulse	I _{DP}	200		
Drain power dissipation (Ta = 25°C)		P _D	100	mW	
Channel temperature		T _{ch}	150	°C	
Storage temperature range		T _{stg}	-55 to 150	°C	

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.



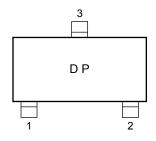
Weight: 2.4 mg (typ.)

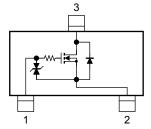
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Marking

Note:

Equivalent Circuit





Handling Precaution

When handling individual devices (which are not yet mounted on a circuit board), be sure that the environment is protected against electrostatic electricity. Operators should wear anti-static clothing, and containers and other objects that come into direct contact with devices should be made of anti-static materials.

Start of commercial production 2001-02

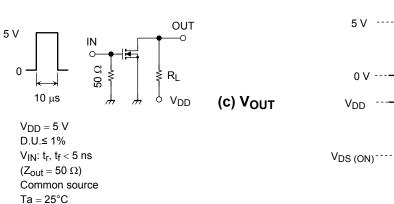
Electrical Characteristics (Ta = 25°C)

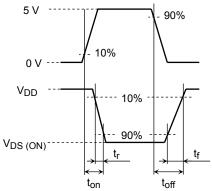
Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current		I _{GSS}	$V_{GS} = \pm 16 \text{ V}, V_{DS} = 0$	_	_	±1	μА
Drain-Source breakdown voltage		V (BR) DSS	$I_D = 0.1 \text{ mA}, V_{GS} = 0$	30	_	_	V
Drain Cut-off current		I _{DSS}	V _{DS} = 30 V, V _{GS} = 0	_	_	1	μА
Gate threshold voltage		V _{th}	$V_{DS} = 3 \text{ V}, I_D = 0.1 \text{ mA}$	0.8	_	1.5	V
Forward transfer admittance		Y _{fs}	$V_{DS} = 3 \text{ V}, I_{D} = 10 \text{ mA}$	25	_	_	mS
Drain-Source ON resistance		R _{DS (ON)}	$I_D = 10 \text{ mA}, V_{GS} = 4 \text{ V}$	_	2.2	4.0	Ω
			I _D = 10 mA, V _{GS} = 2.5 V	_	4.0	7.0	
Input capacitance		C _{iss}	V _{DS} = 3 V, V _{GS} = 0, f = 1 MHz	_	7.8	_	pF
Reverse transfer capacitance		C _{rss}	V _{DS} = 3 V, V _{GS} = 0, f = 1 MHz	_	3.6	_	pF
Output capacitance		Coss	$V_{DS} = 3 \text{ V}, V_{GS} = 0, f = 1 \text{ MHz}$	_	8.8	_	pF
Switching time	Turn-on time	t _{on}	$V_{DD} = 5 \text{ V}, I_D = 10 \text{ mA},$ $V_{GS} = 0 \text{ to } 5 \text{ V}$	_	50	_	ns
	Turn-off time	t _{off}		_	180	_	

Switching Time Test Circuit



(b) V_{IN}



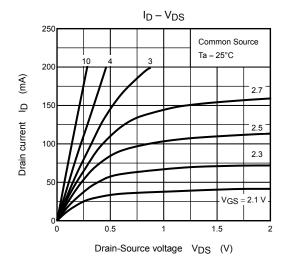


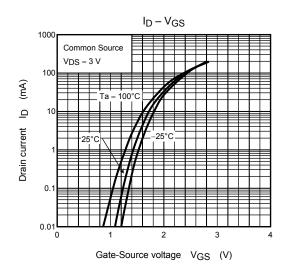
Precaution

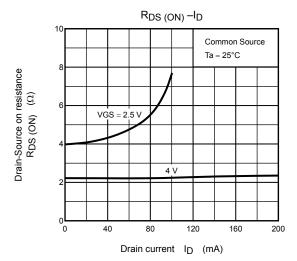
 V_{th} can be expressed as voltage between gate and source when low operating current value is I_D = 100 μA for this product. For normal switching operation, V_{GS} (on) requires higher voltage than V_{th} and V_{GS} (off) requires lower voltage than V_{th} .

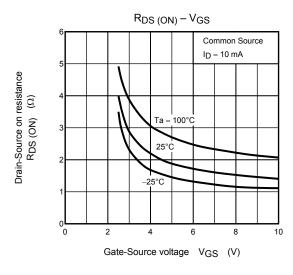
(relationship can be established as follows: $V_{GS}\left(_{off}\right) < V_{th} < V_{GS}\left(_{on}\right)$)

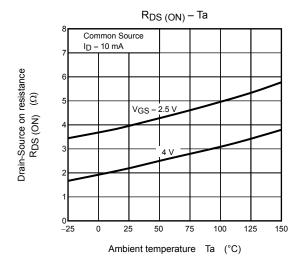
Please take this into consideration for using the device.

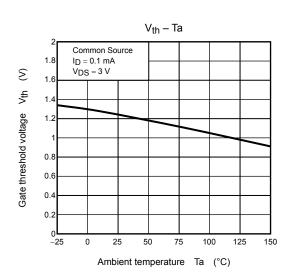


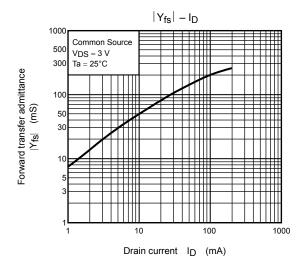


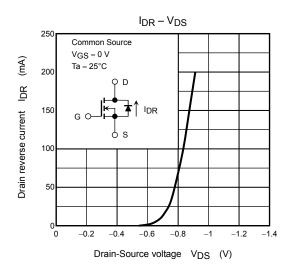


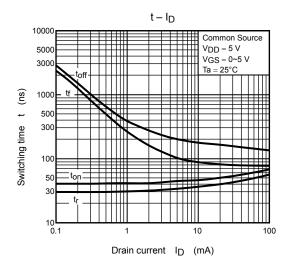


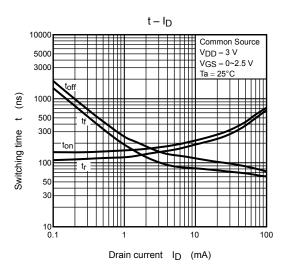


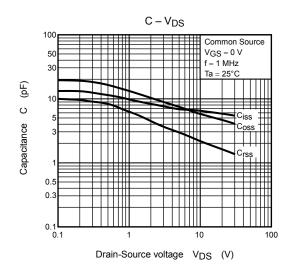


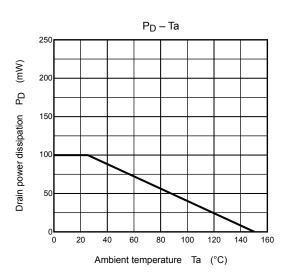












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